# 1.6 $\Omega$ On Resistance, $\pm$ 5 V, $\pm$ 12 V, and $\pm$ 3 V Quad SPST Switches

#### **DESCRIPTION**

The DG9424E, DG9425E, DG9426E are monolithic quad single-pole-single-throw analog switches. The G9424E and DG9425E differ only in that they respond to opposite logic levels. The DG9426E has two normally open and two normally closed switches. It can be given various configurations, including four SPST, two SPDT, and one DPDT.

Using BiCMOS wafer fabrication technology allows the DG9424E, DG9425E, and DG9426E to operate on single and dual supplies. Single supply voltage ranges from 3 V to 16 V while dual supply operation is recommended with  $\pm$  3 V to  $\pm$  8 V. Each switch conducts equally well in both direction when on, and blocks input voltages up to the supply levels when off.

The low and flat on resistance over the full input signal voltage rang bring excellent linearity, reduce insertion loss and signal distortion, make them ideal for data acquisition and programmable gain control applications. These switch characters also make them ideal fit for audio signal switch and reed relay replacement.

The DG9424E, DG9425E, DG9426E feature low power dissipation, fast switching speed, and low voltage logic control threshold. Proprietary design enables the low charge injection that minimize the switching transient.

Operation temperature is specified from -40  $^{\circ}$ C to +85  $^{\circ}$ C. The DG9424E, DG9425E, DG9426E are available in 16 lead TSSOP packages.

#### **FEATURES**

- 3 V to 16 V single supply or ± 3 V thru ± 8 V dual supply operation
- 1.6 Ω typical on resistance
- 3 V logic compatible for control
- · Bi-directional rail to rail signal switching
- · Fast switching speed
- < 0.2 nA switch on leakage</li>
- Break-before-make switching DG9426

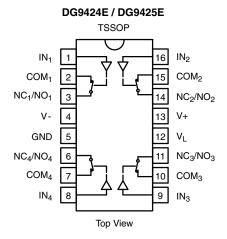
#### **BENEFITS**

- Wide operation voltage range
- · Low signal errors and distortion
- · Fast switching time
- Simple interfacing

#### **APPLICATIONS**

- · Automatic test equipment
- · Data acquisition systems
- · Meters and instruments
- Medical and healthcare systems
- · Communication systems
- Audio and video signal routing
- Relay replacement
- Battery powered systems
- Computer peripherals
- Audio and video signal routing

#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**

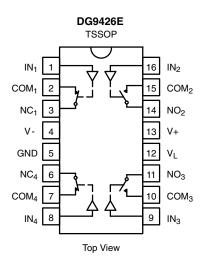


TRUTH TABLE					
LOGIC	DG9424E	DG9425E			
0	OFF	ON			
1	ON	OFF			



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### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



TRUTH TABLE						
LOGIC	SW <sub>1</sub> , SW <sub>4</sub>	SW <sub>2</sub> , SW <sub>3</sub>				
0	ON	OFF				
1	OFF	ON				

ORDERING INFORMATION									
TEMP. RANGE	PACKAGE	PART NUMBER	PART MARKING	STD PACK QUANTITY					
		DG9424EDQ-T1-GE3	9424E	Tape and Reel 3000 Units					
-40 °C to +85 °C	16-Pin TSSOP	DG9425EDQ-T1-GE3	9425E	Tape and Reel 3000 Units					
		DG9426EDQ-T1-GE3	9426E	Tape and Reel 3000 Units					

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		LIMIT	UNIT				
V+ to V-		-0.3 to +18					
GND to V-		18	V				
V <sub>L</sub>		(GND - 0.3) to (V+) + 0.3	V				
IN, COM, NC, NO a		(V-) - 0.3 to (V+) + 0.3					
Continuous Current (NO, NC, COM Pir	s)	100	mA				
Peak Current, S or D (Pulsed 1 ms, 10	% Duty Cycle)	200	IIIA				
Storage Temperature		-65 to +150	°C				
Power Dissipation (Package) b	16-Pin TSSOP °	450	mW				
Thermal Resistance b	16-PIN 1550P 5	178	°C/W				
ESD Human Body Model (HBM); per A	NSI / ESDA / JEDEC® JS-001	>1500	V				
Latch Up Current, per JESD78D		400	mA				

#### Notes

- a. Signals on NC, NO, COM or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 7 mW/°C above 25 °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



SPECIFICATIONS a Single	le Supply 1	2 V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 12 V, V- = 0 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V^f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0	-	12	٧
On-Resistance	R <sub>ON</sub>	V+ = 10.8 V, V- = 0 V	Room	-	1.6	3	Ω
On Hosiotanoo	TION	$I_{NO}$ , $I_{NC} = 50$ mA, $V_{COM} = 2/9$ V	Full	-	-	4	32
Digital Control							
Input Current	I <sub>INL</sub> or I <sub>INH</sub>		Full	-1	0.01	1	μΑ
Dynamic Characteristics							
Turn-On Time <sup>e</sup>	tou		Room	-	36	51	
rum-on mine -	t <sub>ON</sub>	$R_L = 300 \Omega, C_L = 35 pF$	Full	-	-	65	
Turn-Off Time e	$V_{NO}$ , $V_{NC} = 5$ V, see fig. 2	Room	-	20	35	ns	
Turn-Oπ Time °			Full	-	-	44	110
Break-Before-Make Time Delay e	t <sub>D</sub>	DG9426E only, $V_{NO}$ , $V_{NC}$ = 5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	2	-	-	
Charge Injection e	Q <sub>INJ</sub>	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	38	-	рС
Off-Isolation <sup>e</sup>	OIRR	$R_L = 50 \Omega$ , $C_L = 5 pF$	Room	-	-56	-	٩D
Channel-to-Channel Crosstalk e	X <sub>TALK</sub>	f = 1 MHz	Room	-	-77	-	dB
NO NO Off Canacitanas 6	C <sub>NO(off)</sub>		Room	_	49	-	
NO, NC Off Capacitance e	C <sub>NC(off)</sub>	6 d MIL		-			
COM Off Capacitance e	C <sub>COM(off)</sub>	f = 1 MHz	Room	-	37	-	pF
Channel On Capacitance e	C <sub>COM(on)</sub>		Room	-	89	-	
Power Supplies							
Daniti va Covando Covand	1.		Room	-	0.02	1	
Positive Supply Current	l+		Full	-	-	5	
N 0 1 0 1			Room	-1	-0.002	-	
Negative Supply Current	I-	V 2 2 2 4	Full	-5	-	-	_
Lania Comalo Comant	IL	$V_{IN} = 0 \text{ or } V_L$	Room	-	0.002	1	μΑ
Logic Supply Current			Full	-	-	5	
Cround Comment			Room	-1	-0.002	-	
Ground Current	I <sub>GND</sub>		Full	-5	-	-	



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PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 5 V, V- = 5 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V^f$		MIN. d	TYP. c	MAX. d	<b></b>
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	-5		5	V
On-Resistance	R <sub>ON</sub>	V+ = 4.5 V, V- = -4.5 V	Room	-	1.9	3.3	Ω
On-nesistance	TION	$I_{NO}$ , $I_{NC} = 50 \text{ mA}$	Full	-	-	4.3	52
	I <sub>NO(off)</sub>		Room	-1	-	1	
Switch Off Leakage Current	I <sub>NC(off)</sub>	V+ = 5.5 V, V- = -5.5 V	Full	-10	-	10	
Switch Off Leakage Current		$V_{COM} = \pm 4.5 \text{ V}, V_{NO}, V_{NC} = \pm 4.5 \text{ V}$	Room	-1	-	1	nA
	I <sub>COM(off)</sub>		Full	-10	-	10	IIA
Channel On Leakage Current		V+ = 5.5 V, V- = -5.5 V,	Room	-1	-	1	
Channel On Leakage Current	I <sub>COM(on)</sub>	$V_{NO}$ , $V_{NC} = V_{COM} = \pm 4.5 \text{ V}$	Full	-10	-	10	
Digital Control							
Input Current <sup>a</sup>	I <sub>INL</sub> or I <sub>INH</sub>		Full	-1	0.05	1	μΑ
Dynamic Characteristics							
T O. T 0		$R_L = 300~\Omega,~C_L = 35~pF$ $V_{NO},~V_{NC} = \pm~3.5~V,~see~fig.~2$	Room	-	48	67	ns
Turn-On Time <sup>e</sup>	t <sub>ON</sub>		Full	-	-	81	
T O(( T' A	1		Room	-	34	57	
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>		Full	-	-	67	110
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426E only, $V_{NO}$ , $V_{NC}$ = 3.5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	2	-	-	
Charge Injection e	Q <sub>INJ</sub>	$V_{g} = 0 \text{ V}, R_{g} = 0 \Omega, C_{L} = 1 \text{ nF}$	Room	-	112	-	рС
Off Isolation e	OIRR	D 5000 5 7 5 1 MHz	Room	-	-56	-	40
Channel-to-Channel Crosstalk e	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$	Room	-	-82	-	dE
Source Off Capacitance e	$C_{NO(off)} \ C_{NC(off)}$		Room	=	38	-	
Drain Off Capacitance e	C <sub>COM(off)</sub>	f = 1 MHz	Room	-	38	-	рF
Channel On Capacitance e	C <sub>COM(on)</sub>		Room	=.	89	-	
Power Supplies							
Positive Supply Current e	l+		Room	-	0.03	1	
ositive supply current ~	IT		Full	-	-	5	
Negative Supply Current <sup>e</sup>	I-	V 0 27V	Room	-1	-0.002	-	
raogative oupply outlettt -	I=		Full	-5	_	-	μÆ
Logic Supply Current <sup>e</sup>	I.	$V_{IN} = 0$ or $V_L$	Room	-	0.002	1	μ
Logic Supply Current *	lι		Full	-	-	5	[
Craying Courset 6		Room	-1	-0.002	-	[	
Ground Current <sup>e</sup>	I <sub>GND</sub>		Full	-5	-	-	ĺ



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SPECIFICATIONS a Single	e Supply 5	V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 5 V, $V- = 0 VV_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	ı	-	5	V
On-Resistance e	R <sub>ON</sub>	V+ = 4.5 V, I <sub>NO</sub> , I <sub>NC</sub> = 50 mA	Room	-	3.1	4.8	Ω
On-nesistance	HON	v+ = 4.5 v, I <sub>NO</sub> , I <sub>NC</sub> = 50 IIIA	Full	-	-	5.8	52
Dynamic Characteristics							
Turn-On Time <sup>e</sup>	+		Room	-	62	78	
rum-on time °	t <sub>ON</sub>	$R_{L} = 300 \Omega, C_{L} = 35 pF$	Hot	-	-	106	
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>	$V_{NO}$ , $V_{NC} = 3.5 \text{ V}$ , see fig. 2	Room	-	29	44	ns
rum-on nine °			Hot	-	-	56	
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426E only, $V_{NO}$ , $V_{NC}$ = 3.5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	5	-	-	
Charge Injection <sup>e</sup>	Q <sub>INJ</sub>	$V_g$ = 0 V, $R_g$ = 0 $\Omega$ , $C_L$ = 1 nF	Room	-	10	-	рС
Power Supplies							
Docitive Cumply Current 6			Room	-	0.02	1	
Positive Supply Current <sup>e</sup>	I+		Hot	-	-	5	
Negative Cumply Cument 6	I-		Room	-1	-0.002	-	
Negative Supply Current <sup>e</sup>	I-	V 0 0"V	Hot	-5	-	-	
Logio Supply Current 6	ı.	$V_{IN} = 0$ or $V_L$	Room	-	0.002	1	μΑ
Logic Supply Current <sup>e</sup>	IL .		Hot	ı	-	5	
Ground Current <sup>e</sup>	la.:-		Room	-1	-0.002	-	
Ground Current °	$I_{GND}$		Hot	-5	-	-	



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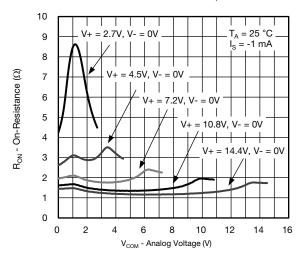
SPECIFICATIONS a Sing	le Supply 3	V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 3 V, V- = 0 V $V_L = 3 V, V_{IN} = 2.4 V, 0.4 V f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog Signal Range e	V <sub>ANALOG</sub>		Full	0	-	3	٧
On-Resistance	R <sub>ON</sub>	V+ = 2.7 V, V- = 0 V	Room	ı	6	-	Ω
Oli-nesistance	HON	$I_{NO}$ , $I_{NC} = 5$ mA, $V_{COM} = 0.5$ , 2.2 V	Full	ı	-	-	22
	I <sub>NO(off)</sub>		Room	-1	-	1	
Switch Off Leakage Current a	I <sub>NC(off)</sub>	V+ = 3.3 V, V- = 0 V	Full	-10	-	10	
Switch On Leakage Current "		$V_{COM} = 0.3, 3 \text{ V}, V_{NO}, V_{NC} = 3, 0.3 \text{ V}$	Room	-1	-	1	
	ICOM(off)		Full	-10	-	10	nA
Channal On Lookaga Current 8		V+ = 3.3 V, V- = 0 V, V <sub>NO</sub> , V <sub>NC</sub> = V <sub>COM</sub> = 0.3, 3 V	Room	-1	-	1	-
Channel On Leakage Current <sup>a</sup>	I <sub>COM(on)</sub>		Full	-10	-	10	
Digital Control e							
Input Current	I <sub>INL</sub> or I <sub>INH</sub>		Full	-1	0.005	1	μΑ
Dynamic Characteristics							
Turn-On Time	4		Room	ı	140	-	
rum-on rime	t <sub>ON</sub>	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	Full	ı	-	193	
Turn-Off Time		$V_{NO}$ , $V_{NC} = 1.5 \text{ V}$ , see fig. 2	Room	1	65	-	ns
rum-on rime	t <sub>OFF</sub>		Full	-	-	89	
Break-Before-Make Time Delay	t <sub>D</sub>	DG9426E only, $V_{NO}$ , $V_{NC}$ = 1.5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	5			
Charge Injection e	Q <sub>INJ</sub>	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	15	-	рС
Off Isolation e	OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room	-	-56	-	dB
Channel-to-Channel Crosstalk e	X <sub>TALK</sub>	f = 1 MHz	Room	-	-80	-	иь
Caura Off Canacitanas 6	C <sub>NO(off)</sub>		Doom	_	F0		
Source Off Capacitance e	C <sub>NC(off)</sub>	f _ 1 MU-	Room	-	53	_	nE
Drain Off Capacitance e	C <sub>COM(off)</sub>	f = 1 MHz	Room	-	42	-	pF
Channel On Capacitance e	C <sub>COM(on)</sub>		Room	-	92	-	

#### Notes

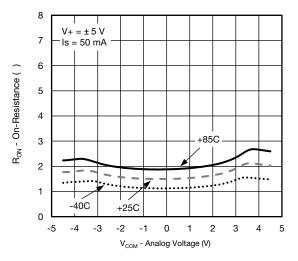
- a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test.
- b. Room = 25 °C, Full = As determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- e. Guaranteed by design, not subject to production test.
- f.  $V_{IN}$  = Input voltage to perform proper function.

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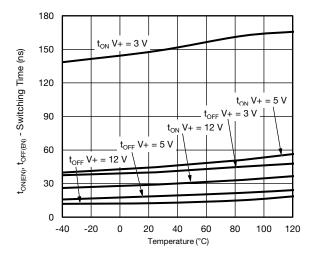
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



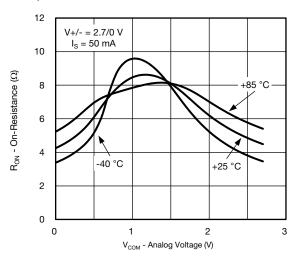
R<sub>ON</sub> vs. V<sub>COM</sub> and Supply Voltage



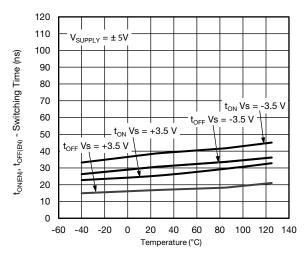
R<sub>ON</sub> vs. Analog Voltage and Temperature



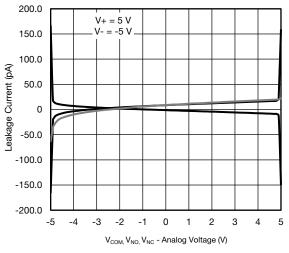
Switching Time vs. Temperature and Single Supply Voltage



 $R_{\mbox{\scriptsize ON}}$  vs. Analog Voltage and Temperature



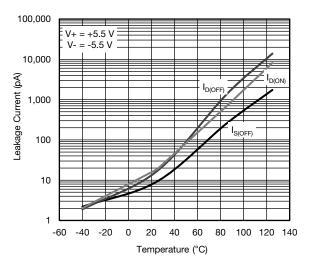
Switching Time vs. Temperature and Dual Supply Voltage



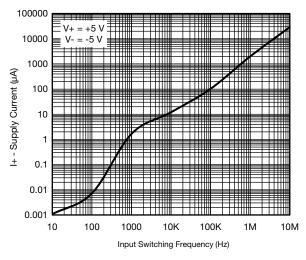
Leakage Current vs. Analog Voltage

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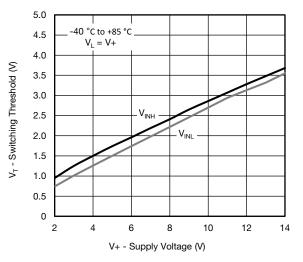
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



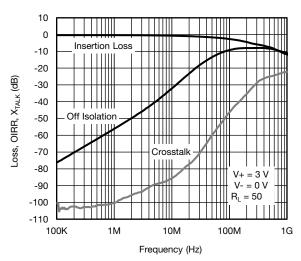
Leakage Current vs. Temperature



**Switching Current vs. Input Switching Frequency** 



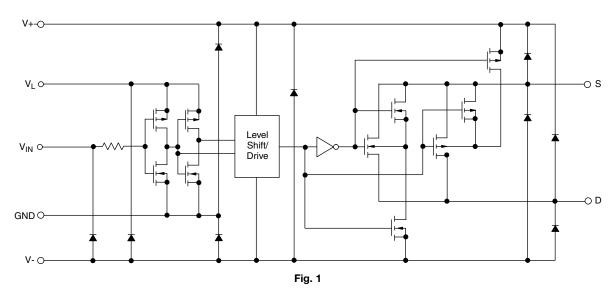
Switching Threshold vs. Supply Voltage



Insertion Loss, Off Isolation and Crosstalk vs. Frequency

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### **SCHEMATIC DIAGRAM** (typical channel)



#### **TEST CIRCUITS**

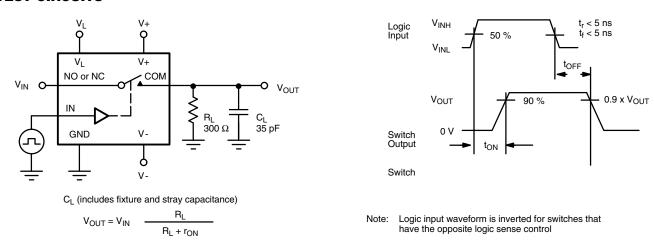


Fig. 2 - Switching Time

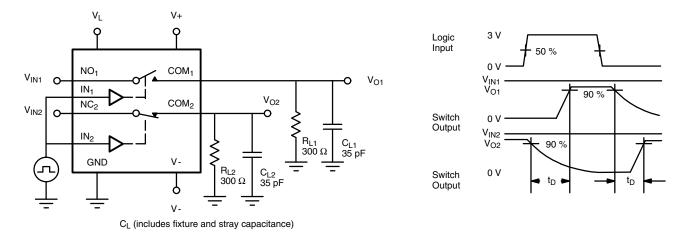
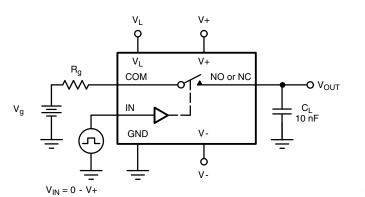
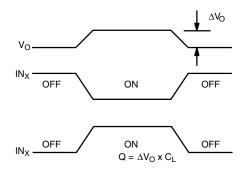


Fig. 3 - Break-Before-Make (DG9426E)

#### **TEST CIRCUITS**





 $\ensuremath{\mathsf{IN}}_X$  dependent on switch configuration Input polarity determined by sense of switch.

Fig. 4 - Charge Injection

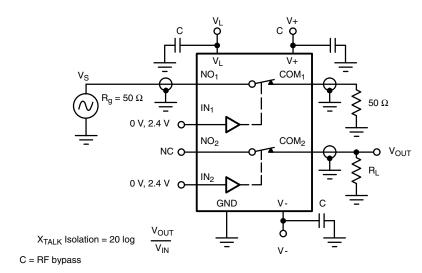


Fig. 5 - Crosstalk

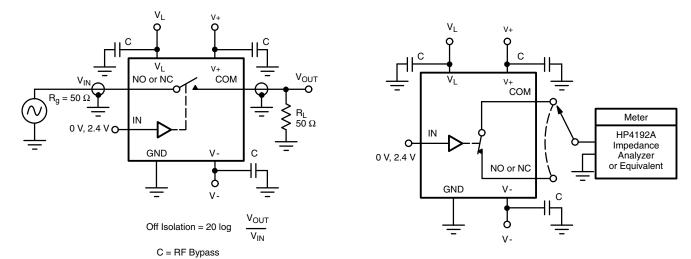


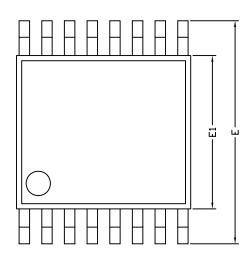
Fig. 6 - Off-Isolation

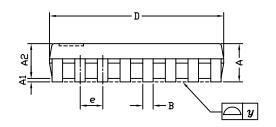
Fig. 7 - Source/Drain Capacitances

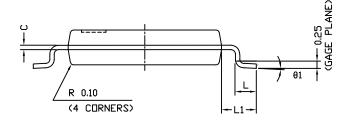
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**TSSOP: 16-LEAD** 







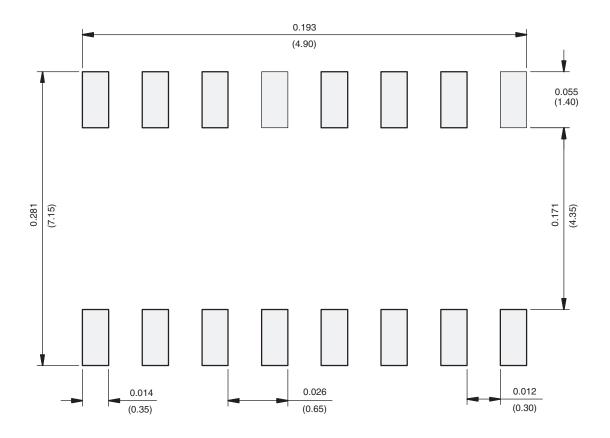
	DII	MENSIONS IN MILLIMETE	RS
Symbols	Min	Nom	Max
А	=	1.10	1.20
A1	0.05	0.10	0.15
A2	=	1.00	1.05
В	0.22	0.28	0.38
С	=	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
е	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
у	=	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D. 23-0	Oct-06	<u> </u>	

DWG: 5624

Document Number: 74417 www.vishay.com 23-Oct-06



### **RECOMMENDED MINIMUM PAD FOR TSSOP-16**



Recommended Minimum Pads Dimensions in inches (mm)



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